Results on Opto-Link R&D

W. Fernando, K.K. Gan, A. Law, H.P. Kagan, R.D. Kass, J. Moore, A. Rau, S. Smith
The Ohio State University

M.R.M. Lebbai, P.L. Skubic
University of Oklahoma

B. Abi, F. Rizatdinova
Oklahoma State University

Oct 3, 2008

Outline

- Radiation hardness of PIN arrays

- Radiation hardness of VCSEL arrays

- Study of opto-chips

- Summary

Opto-Link at SLHC

- ATLAS is a detector studying pp collisions of 14 TeV at CERN
  - silicon detectors use opto-links for data transmission
  - pixel detector is innermost tracker
  - new barrel layer with smaller radius planned in 2013
  - detectors upgrade planned for Super-LHC in 2016
  - ⇨ study radiation-hardness of VCSEL and PIN arrays
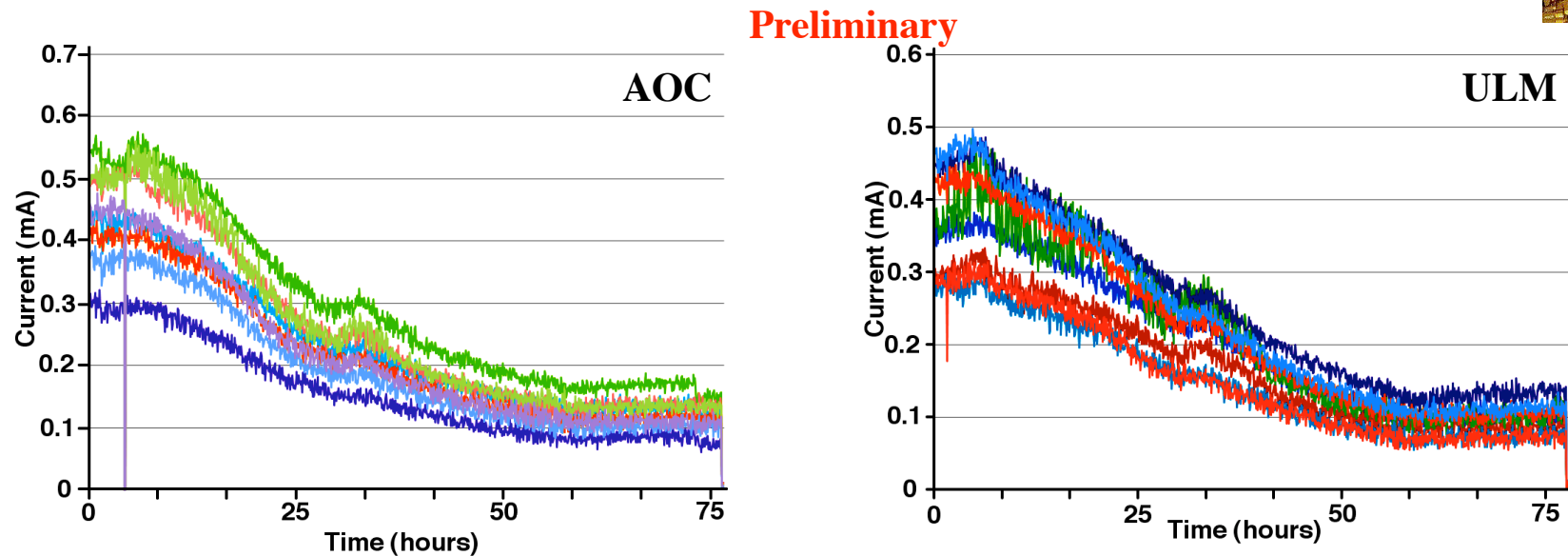   and opto-chips for the opto-link upgrades

Radiation-Hardness of Silicon PIN

Preliminary
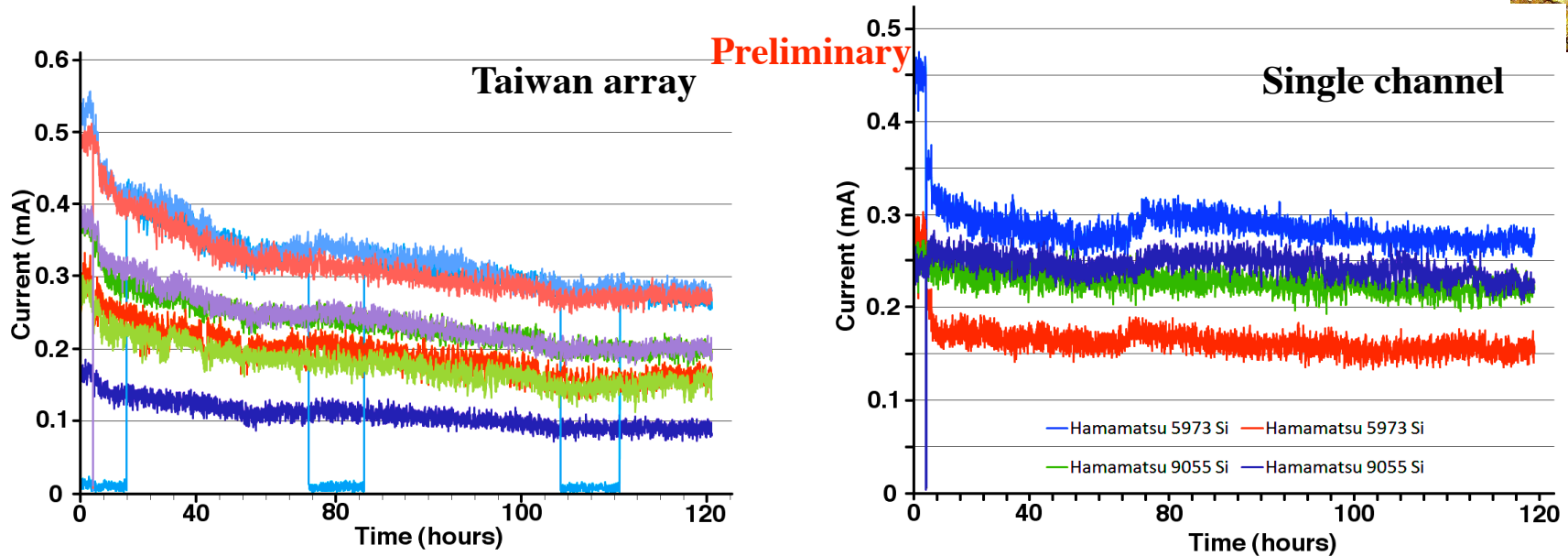
- irradiate PIN with 24 GeV protons at CERN
  - SLHC dosage: 2.6×10^{15} p/cm^2 (1.5×10^{15} 1-MeV n$_{eq}$/cm^2)
  - 2007 irradiation with 60% higher dosage:
    - Taiwan array responsivity (A/W): decrease by a factor of 3
  - 2008 irradiation with SLHC dosage:
    - Taiwan array responsivity: decrease by a factor of 2
    - Hamamatsu device responsivity: decrease somewhat less
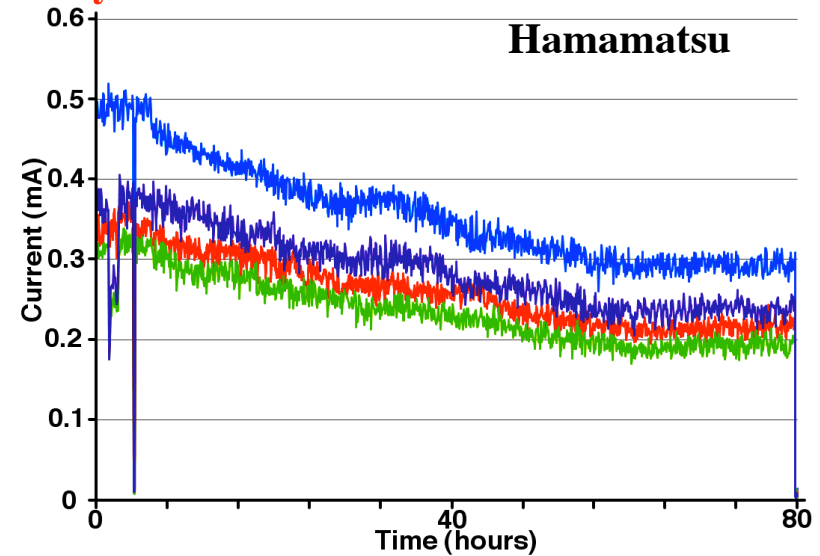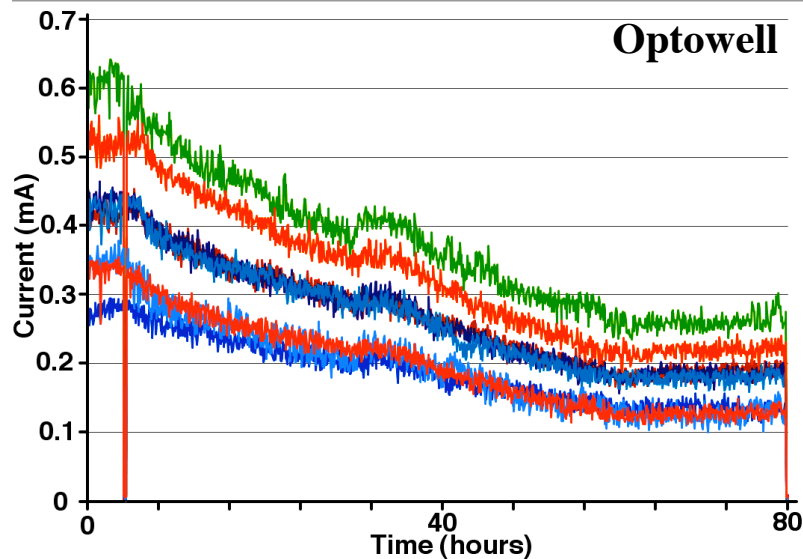
Radiation-Hardness of GaAs PIN

- irradiate PIN with 24 GeV protons at CERN
  - SLHC dosage: 2.6×10^{15} p/cm^2 (8.2×10^{15} 1-MeV n_{eq}/cm^2)
  - 2007 irradiation with 60% higher dosage:
    - responsivity: decrease by a factor of 10
  - 2008 irradiation with SLHC dosage:
    - responsivity: decrease by a factor of 2-4

Radiation-Hardness of GaAs PIN

- 2007 irradiation with 60% higher dosage:
  - Optowell responsivity: decrease by a factor of 10
- 2008 irradiation with SLHC dosage:
  - Optowell responsivity: decrease by a factor of ~2
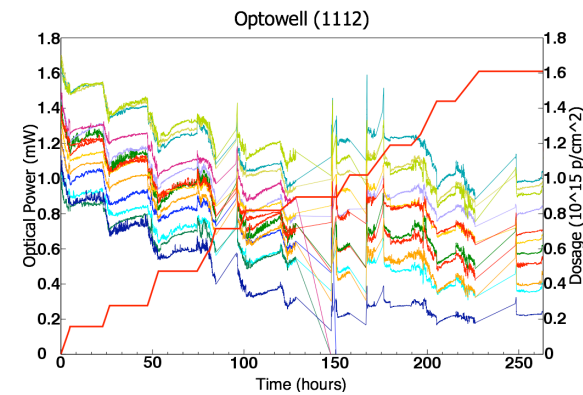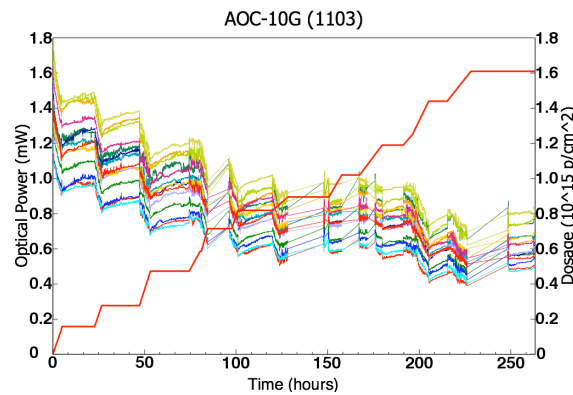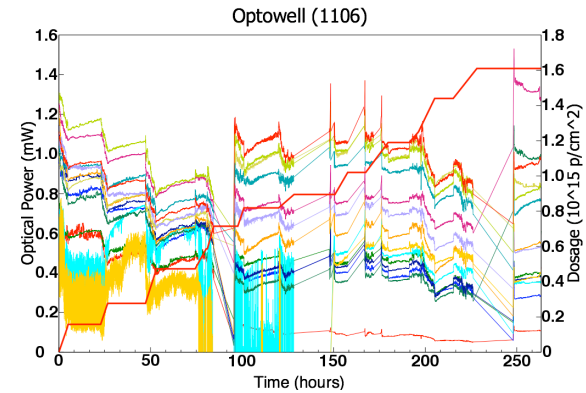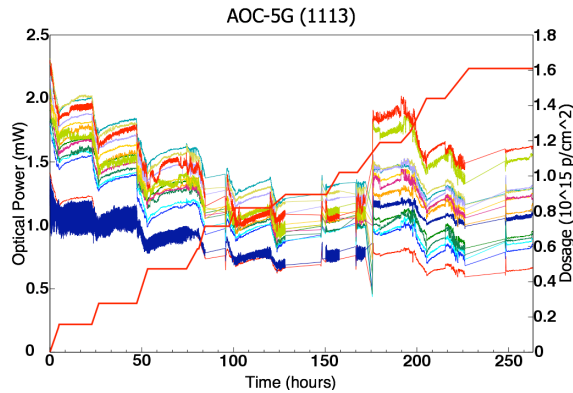 - Hamamatsu responsivity: decrease by a factor of ~1.6

Radiation-Hardness of PIN

	Gb/s	Responsivity (A/W)	
		Pre	Post
GaAs			
ULM	4.25	0.50	0.13
AOC	2.5	0.60	0.19
Optowell	3.125	0.60	0.25
Hamamatsu G8921	2.5	0.50	0.32
Si			
Taiwan	1.0	0.55	0.33
Hamamatsu S5973	1.0	0.47	0.37
Hamamatsu S9055	1.5/2.0	0.25	0.21

VCSEL Power vs Dosage

- 2007 irradiation with 60% higher dosage:
  - close to zero power on some channels
- 2008 irradiation with SLHC dosage:
  - AOC(5 & 10 G) have good power
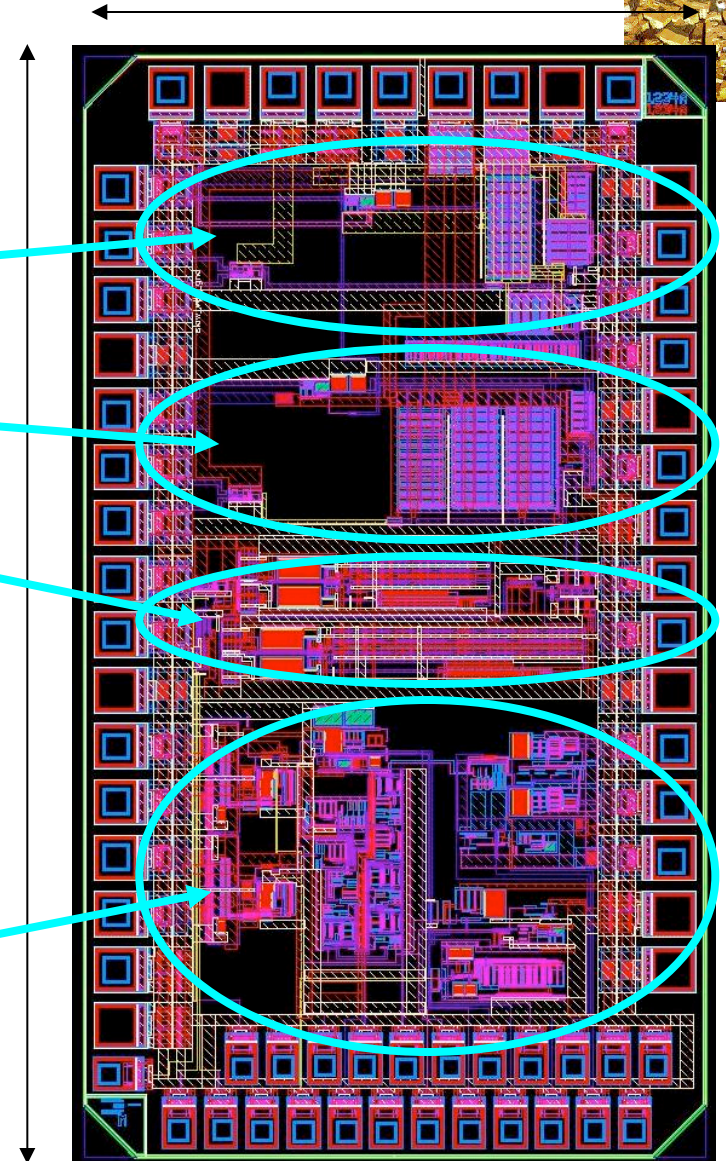
Opto-Chips

1.5 mm

0.13 μm

640 Mb/s VCSEL Driver

3.2 Gb/s VCSEL Driver

640 MHz clock multipliers
(4 x 160 and 16 x 40 MHz)

2.6 mm

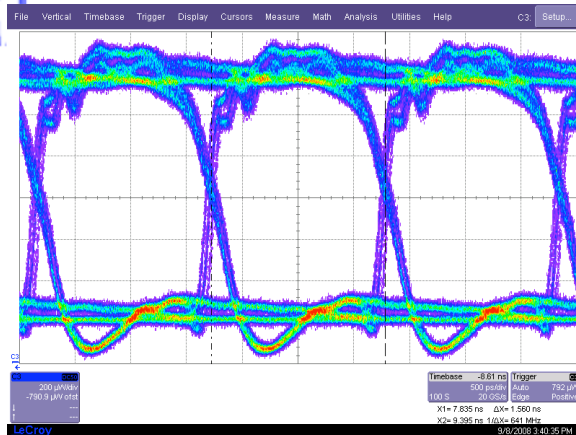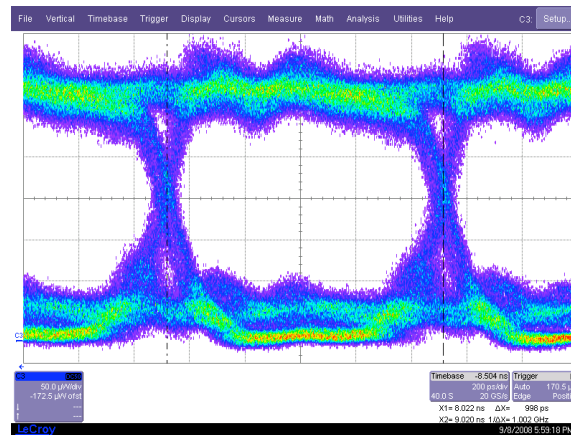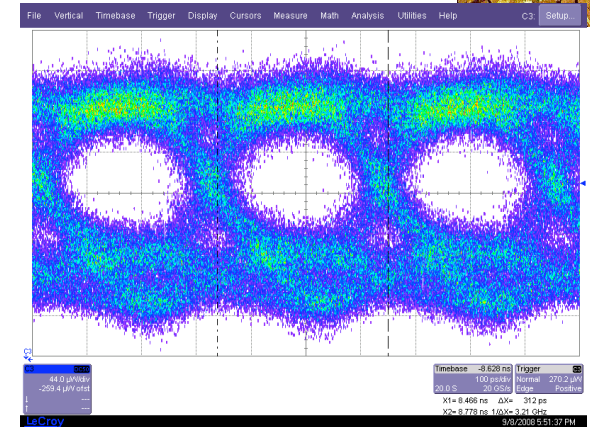PIN receiver/decoder
(40, 160, 320 MHz)

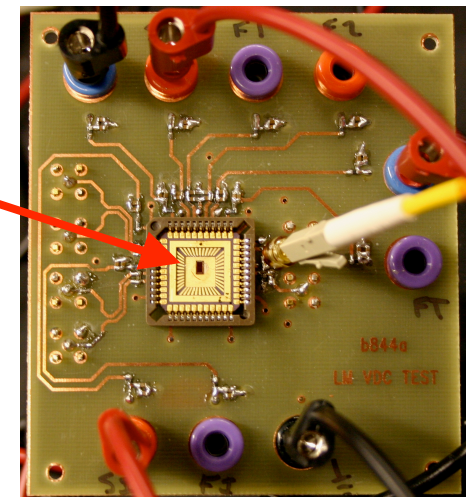# VCSEL Driver Chip

Slow VDC
640 Mb/s

Fast VDC
1 Gb/s

Fast VDC
3.2 Gb/s

PLCC
package

- both chips are working in preliminary study
- LVDS receiver working at high speed
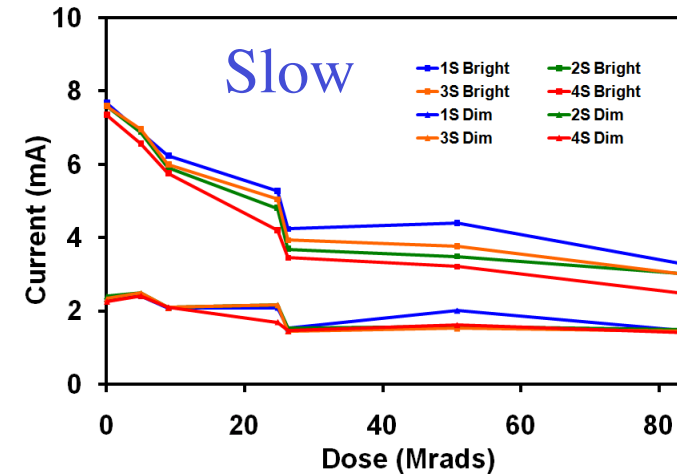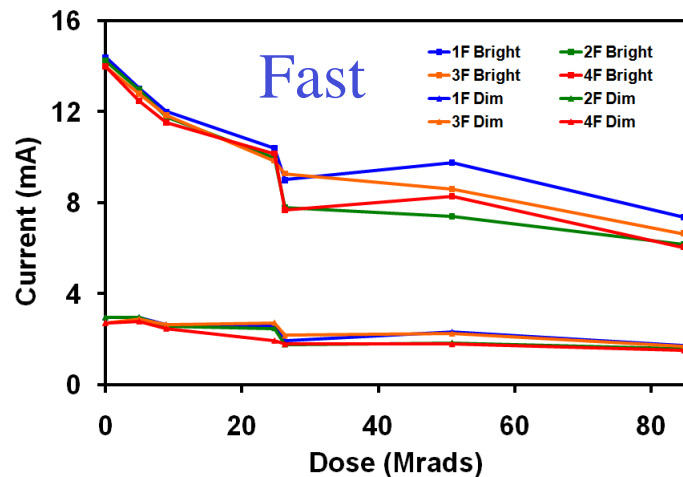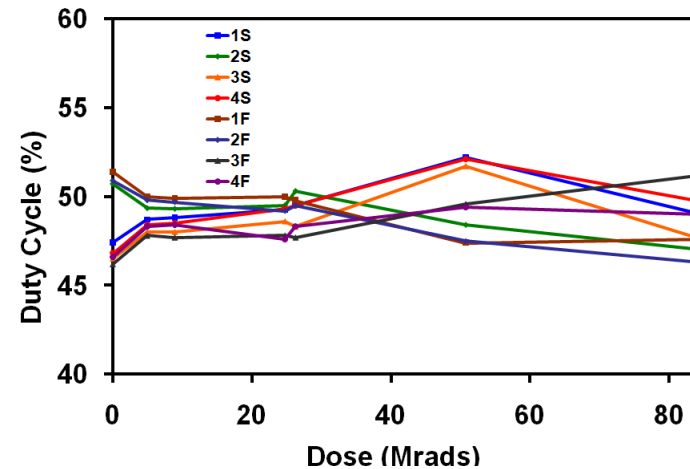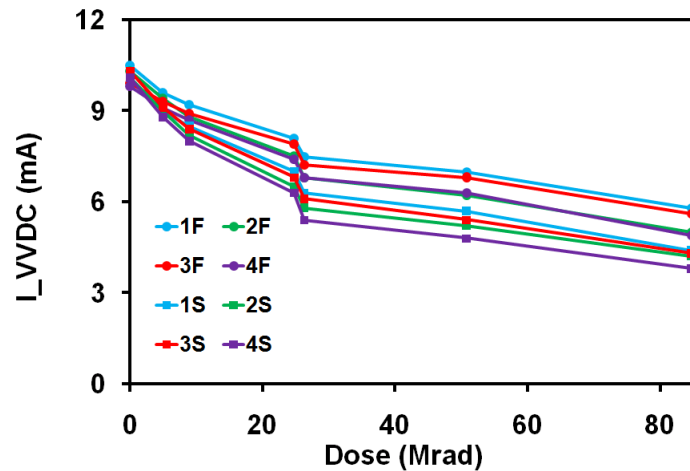- need detailed study without package
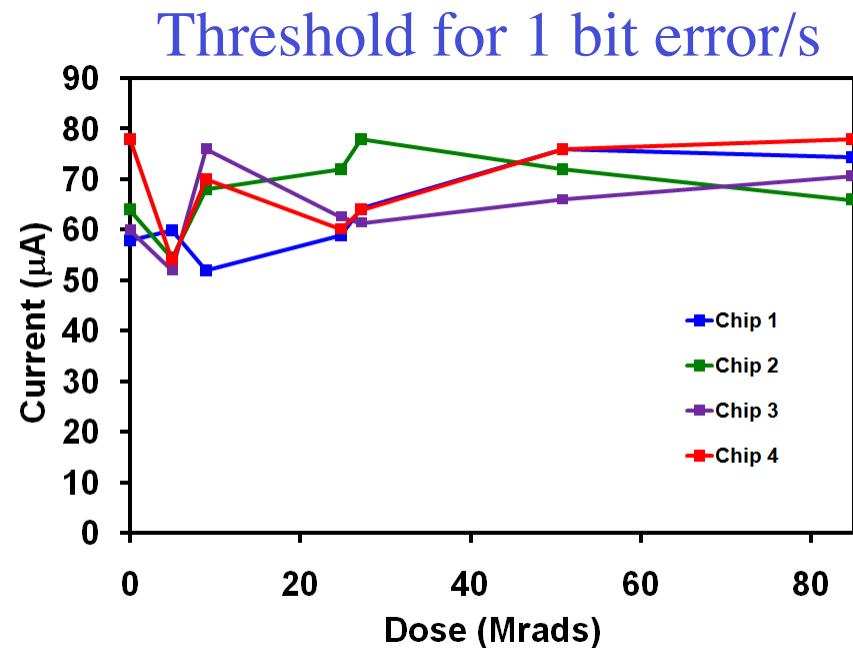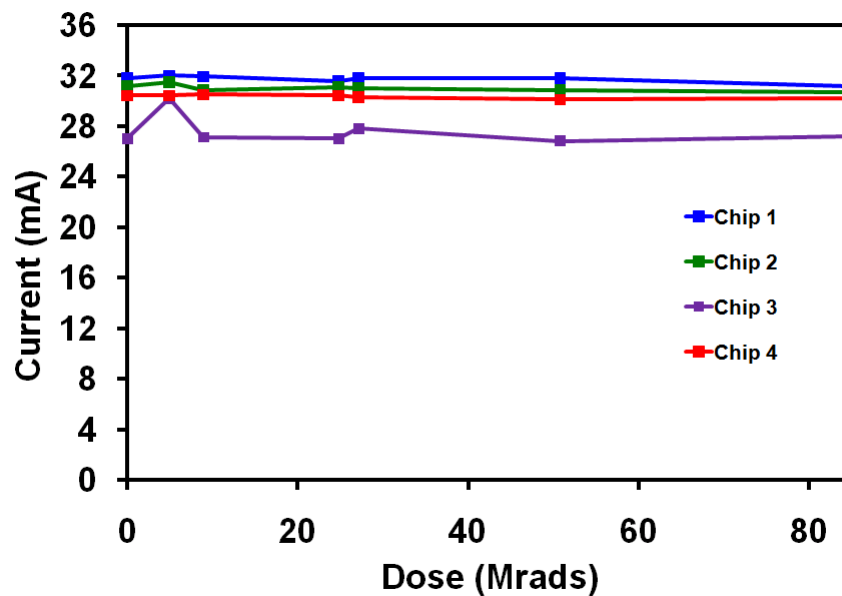
VDC Irradiation

- drive current decreases with radiation for constant ISET
- need detailed study after cool down

Receiver/Decoder Chip

- Properly decode 40, 80, and 160 Mb/s signals but not 320 Mb/s
  - LVDS-like output has proper amplitude and baseline
  - small clock jitter (e.g. < 50 ps @ 160 MHz)
  - no significant degradation after irradiation
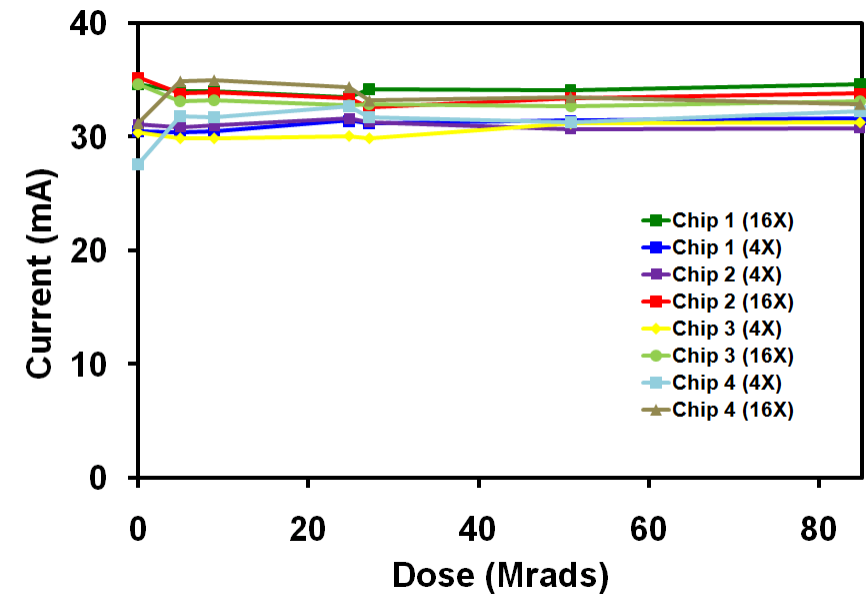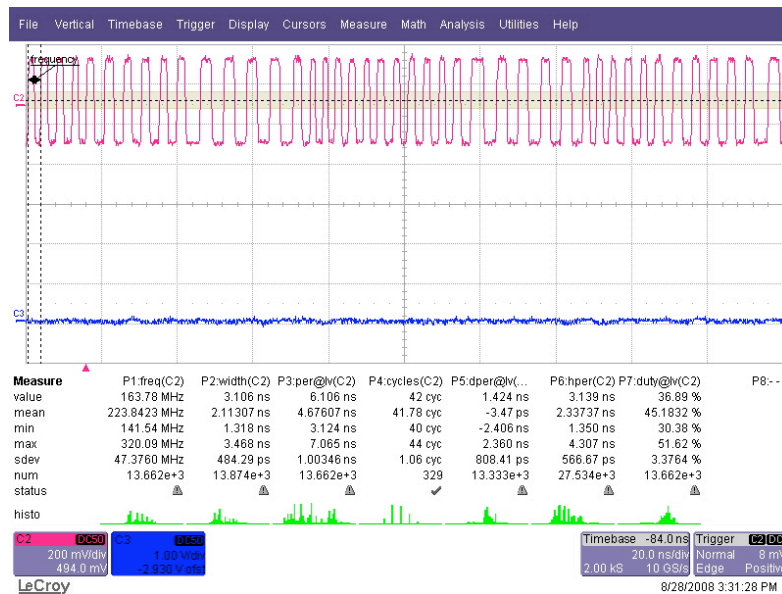
Threshold for 1 bit error/s

Clock Multiplier

- Both 4 x and 16 x clock multipliers work
  - ◆ clock jitter < 8 ps (0.5%)
  - ◆ two of the four chips lost lock during irradiation
    - ❏ need power cycling to resume operation at 640 MHz
  - ◆ no change in current consumption

Summary

- Good PIN candidates identified for SLHC opto-link

- Good VCSEL candidates identified for SLHC opto-link

- First 0.13 μm submission mostly successful
  - full characterization of pre/post irradiation in progress
  - aim for next iteration in winter 2009